



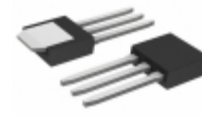





	GP2M002A060FG	
	Hersteller-Teilenummer:	GP2M002A060FG
	Hersteller / Marke:	Global Power Technologies Group
	Teil der Beschreibung:	MOSFET N-CH 600V 2A TO220F
	Datenblätter:	 GP2M002A060FG.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 1859 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	GP2M002A060FG
Hersteller	Global Power Technologies Group
Beschreibung	MOSFET N-CH 600V 2A TO220F
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	1859 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3 Full Pack
Supplier Device-Gehäuse	TO-220F
Verlustleistung (max)	17.3W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2A (Tc)
Rds On (Max) @ Id, Vgs	4 Ohm @ 1A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	9nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	360pF @ 25V
Verpackung	Tube

GP2M002A060FG ist neu im Original, Suche GP2M002A060FG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie GP2M002A060FG Global Power Technologies Group mit Garantie und Vertrauen. Anfrage GP2M002A060FG: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>GP2L24J0000F Sharp Microelectronics PHOTOINTERRUPTER REFLEC .7MM PCB</p>	 <p>GP2L26K2 KODENSHI GP2L26K2 KODENSHI</p>	 <p>GP2M002A060PG Global Power Technologies Group MOSFET N-CH 600V 2A</p>	 <p>GP2M002A065FG Global Power Technologies Group MOSFET N-CH 650V 1.8A TO220F</p>
 <p>GP2M002A065CG Global Power Technologies Group MOSFET N-CH 650V 1.8A DPAK</p>	 <p>GP2M002A060HG Global Power Technologies Group MOSFET N-CH 600V 2A TO220</p>	 <p>GP2L24CJ00F Sharp Microelectronics PHOTOINTERRUPTER REFLEC .8MM PCB</p>	 <p>GP2M002A060CG Global Power Technologies Group MOSFET N-CH 600V 2A DPAK</p>

heiße Teile

Mehr

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|--|--|---|---|---|
|  GP200E1M-G1 |  GP200E1MTR-G1 |  GP200EMTR-G1 |  GP200MTR-G1 |  GP2A231LRSA |
|  GP2A25J0000F |  GP2A25J0000F |  GP2A25NJ |  GP2A28A1J00F |  GP2A28N1J00F |
|  GP2AP002A00F |  GP2AP002S00F |  GP2AP003A10F |  GP2AP007A00F |  GP2AP008T00F |
|  GP2AP030A00F |  GP2AP052A00F |  GP2AP052A00F |  GP2L26K2 |  GP2M004A060PG |
|  GP2M004A065FG |  GP2M004A065PG |  GP2M005A050PG |  GP2M005A060CG |  GP2M005A060FG |
|  GP2M005A060PGH |  GP2M008A060FGH |  GP2M010A060F |  GP2M010A065F |  GP2M011A090NG |
|  GP2M012A080NG |  GP2M020A050H |  GP2M020A060N |  GP2S24J0000F |  GP2S27T3 |
|  GP2S27T3J00F |  GP2S27V6 |  GP2S29SVJ00F |  GP2S40JJ000F |  GP2S700HCP |
|  GP2S700HCP |  GP2W0004YP |  GP2W0110YPS |  GP2W0112YPOF |  GP2W0118YPS |
|  GP2W0150YP0F |  GP2W3104XP0F |  GP2W3104YP0F |  GP2W3106YP0F |  GP2W3152YP0F |

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